■ MN101E01J, MN101E01K, MN101E01L, MN101E01M

Туре	MN101E01J	MN101E01K	MN101E01L	MN101E01M	MN101EF01M	
Internal ROM type		FLASH				
ROM (byte)	192K	256K	320K	384K		
RAM (byte)	10K		14K	20K	24K	
Package (Lead-free)	QFP100-P-1818B LQFP100-P-1414, QFP100-				P-1818B	
Minimum Instruction Execution Time	62.5 μs (at 3.0 V to 3.6 V, 32 kHz) [Double speed]				[Standard] 0.0625 μs (at 3.0 V to 3.6 V, 32 MHz) [Double speed] 0.10 μs (at 3.0 V to 3.6 V, 10 MHz)	

Interrupts

RESET, Watchdog, External 0 to 5, Timer 0 to 6, Timer 7 (2 systems), Time base, Serial 0 (2 systems), Serial 1 (2 systems), Serial 2, Serial 3, Serial 4 (2 systems), Automatic transfer finish, A/D conversion finish, Key interrupts (8 lines)

■ Timer Counter

Timer counter 0 : 8-bit \times 1

(square-wave/8-bit PWM output, event count, generation of remote control carrier, pulse width measurement, generation of real time)

Interrupt source coincidence with compare register 0

Timer counter 1 : 8-bit × 1 (square-wave output, event count, synchronous output event)

XI oscillation clock frequency; external clock input

Interrupt source coincidence with compare register 1

Timer counter 0, 1 can be cascade-connected.

Timer counter 2: 8-bit \times 1

(square-wave/8-bit PWM output, event count, synchronous output event, pulse width measurement generation of real time, serial baud rate timer)

XI oscillation clock frequency; external clock input

Interrupt source coincidence with compare register 2

Timer counter 3:8-bit × 1

(square-wave output, event count, generation of remote control carrier, serial baud rate timer)

XI oscillation clock frequency; external clock input

Interrupt source coincidence with compare register 3

Timer counter 2, 3 can be cascade-connected.

Timer counter 4:8-bit \times 1

(square-wave/8-bit PWM output, event count, pulse width measurement, serial baud rate timer)

XI oscillation clock frequency; external clock input frequency

Interrupt source coincidence with compare register 4

Timer counter 5 : 8-bit × 1 (square-wave output, event count, serial baud rate timer)

XI oscillation clock frequency; external clock input

Interrupt source coincidence with compare register 5

Timer counter 4, 5 can be cascade-connected.

MN101E01J, MN101E01K, MN101E01L, MN101E01M □

Timer counter 6: 8-bit freerun timer

1/8192 of XI oscillation clock frequency

Interrupt source coincidence with compare register 6

Timer counter 7: 16-bit × 1

(square-wave/16-bit PWM output, cycle / duty continuous variable, event count, synchronous output evevt, pulse width measurement, input capture)

1/2, 1/4, 1/16 of external clock input frequency

Interrupt source coincidence with compare register 7 (2 lines)

Time base timer (one-minute count setting)

Watchdog timer

Interrupt source 1/65536, 1/262144, 1/1048576, 1/4194304 of system clock frequency

Serial interface

Serial 0 : synchronous type/UART (full-duplex) × 1

Serial 1: synchronous type/UART (full-duplex) × 1

Serial 2 : synchronous type/single-master I²C× 1

Serial 3: synchronous type/single-master I²C × 1

Serial 4 : synchronous type/UART (full-duplex) × 1

■ DMA controller

Max. Transfer cycles: 255

Starting factor: external request, various types of interrupt, software

Transfer mode: 1-byte transfer, word transfer, burst transfer

■ I/O Pins

I/O	34	(5 V IF port) Common use, Specified pull-up resistor available, Input/output selectable (bit unit)
	50	(3 V IF port) Common use, Specified pull-up resistor available, Input/output selectable (bit unit)

■ A/D converter

10-bit \times 8-ch. (with S/H)

■ D/A converter

8-bit \times 1-ch.

Special Ports

Buzzer output, remote control carrier signal output, high-current drive port

■ ROM Correction

Correcting address designation: up to 3 addresses possible

■ Electrical Charactreistics (Supply current)

Parameter	Symbol	Condition		Limit		
- Farameter				typ	max	Unit
Operating supply current	IDD1	fosc = 32.0 MHz, $VDD1 = 3.3 V$, $(fs = fosc/2)$		11 (48)	30 (80)	mA
	IDD2	fosc = 20.0 MHz, $VDD1 = 3.3 V$, $(fs = fosc/2)$		8 (43)	22 (75)	mA
	IDD3	fosc = 32.768 kHz, VDD1 = 3.3 V, (fs = fosc/2)		30 (60)	120 (180)	μΑ
Supply current at HALT	IDD4	fx = 32.768 kHz , VDD1 = 3.3 V		12	30	μΑ
Supply current at STOP	IDD5	VDD1 = 3.3 V , Ta = 25°C		0.3	3.0	μΑ
	IDD6	VDD1 = 3.3 V , Ta = 85°C			80	μΑ

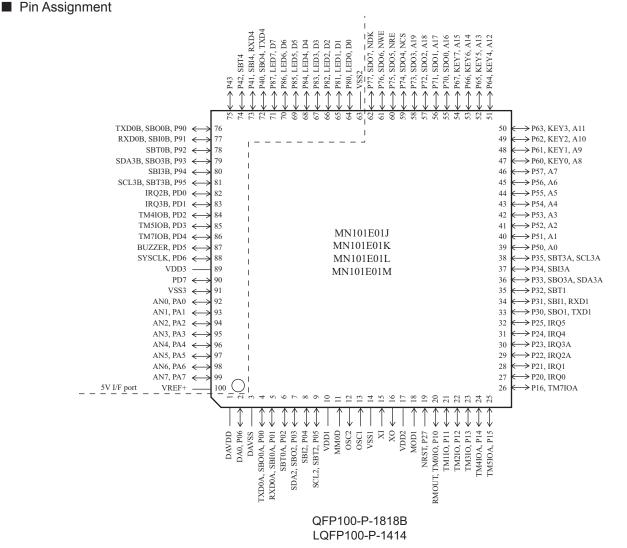
(): Flash memory built-in type

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■ Development tools

In-circuit Emulator

PX-ICE101E+PRBV101E01-QFP100-P-1818B PX-ICE101E+PRBV101E01-LQFP100-P-1414



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